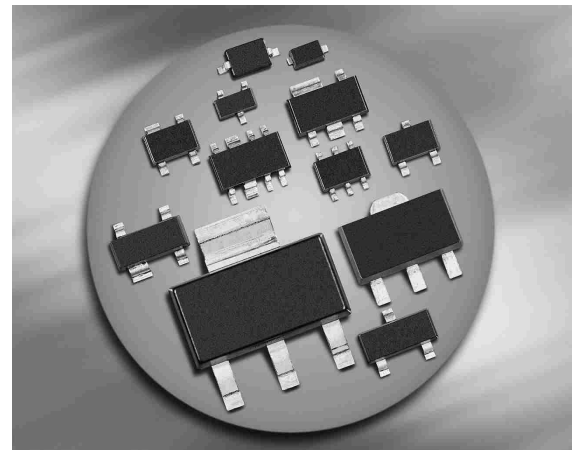


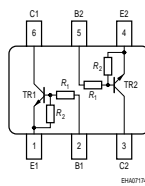
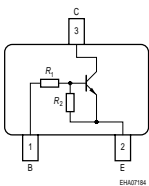
**NPN Silicon Digital Transistor**

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ( $R_1=4.7\text{ k}\Omega$ ,  $R_2=47\text{ k}\Omega$ )
- BCR116S: Two internally isolated transistors with good matching in one multichip package
- BCR116S: For orientation in reel see package information below
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101



**BCR116**  
**BCR116W**

**BCR116S**



| Type    | Marking | Pin Configuration |      |      |      |      |      | Package |
|---------|---------|-------------------|------|------|------|------|------|---------|
|         |         | 1=B               | 2=E  | 3=C  | -    | -    | -    |         |
| BCR116  | WG5     | 1=B               | 2=E  | 3=C  | -    | -    | -    | SOT23   |
| BCR116S | WG5     | 1=E1              | 2=B1 | 3=C2 | 4=E2 | 5=B2 | 6=C1 | SOT363  |
| BCR116W | WG5     | 1=B               | 2=E  | 3=C  | -    | -    | -    | SOT323  |

**Maximum Ratings**

| Parameter                                                                                                                                          | Symbol       | Value             | Unit |
|----------------------------------------------------------------------------------------------------------------------------------------------------|--------------|-------------------|------|
| Collector-emitter voltage                                                                                                                          | $V_{CEO}$    | 50                | V    |
| Collector-base voltage                                                                                                                             | $V_{CBO}$    | 50                |      |
| Input forward voltage                                                                                                                              | $V_{i(fwd)}$ | 30                |      |
| Input reverse voltage                                                                                                                              | $V_{i(rev)}$ | 5                 |      |
| Collector current                                                                                                                                  | $I_C$        | 100               | mA   |
| Total power dissipation-<br>BCR116, $T_S \leq 102^\circ\text{C}$<br>BCR116S, $T_S \leq 115^\circ\text{C}$<br>BCR116W, $T_S \leq 124^\circ\text{C}$ | $P_{tot}$    | 200<br>250<br>250 | mW   |
| Junction temperature                                                                                                                               | $T_j$        | 150               | °C   |
| Storage temperature                                                                                                                                | $T_{stg}$    | -65 ... 150       |      |

**Thermal Resistance**

| Parameter                                | Symbol     | Value      | Unit |
|------------------------------------------|------------|------------|------|
| Junction - soldering point <sup>1)</sup> | $R_{thJS}$ |            | K/W  |
| BCR116                                   |            | $\leq 240$ |      |
| BCR116S                                  |            | $\leq 140$ |      |
| BCR116W                                  |            | $\leq 105$ |      |

<sup>1</sup>For calculation of  $R_{thJA}$  please refer to Application Note AN077 (Thermal Resistance Calculation)

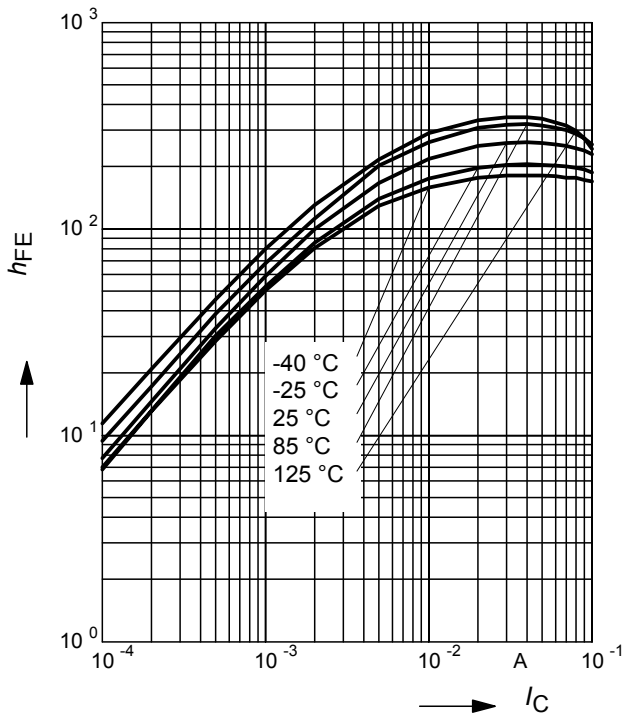
**Electrical Characteristics at  $T_A = 25^\circ\text{C}$ , unless otherwise specified**

| Parameter                                                                                         | Symbol        | Values |      |      | Unit             |
|---------------------------------------------------------------------------------------------------|---------------|--------|------|------|------------------|
|                                                                                                   |               | min.   | typ. | max. |                  |
| <b>DC Characteristics</b>                                                                         |               |        |      |      |                  |
| Collector-emitter breakdown voltage<br>$I_C = 100\ \mu\text{A}, I_B = 0$                          | $V_{(BR)CEO}$ | 50     | -    | -    | V                |
| Collector-base breakdown voltage<br>$I_C = 10\ \mu\text{A}, I_E = 0$                              | $V_{(BR)CBO}$ | 50     | -    | -    |                  |
| Collector-base cutoff current<br>$V_{CB} = 40\ \text{V}, I_E = 0$                                 | $I_{CBO}$     | -      | -    | 100  | nA               |
| Emitter-base cutoff current<br>$V_{EB} = 5\ \text{V}, I_C = 0$                                    | $I_{EBO}$     | -      | -    | 155  | $\mu\text{A}$    |
| DC current gain <sup>1)</sup><br>$I_C = 5\ \text{mA}, V_{CE} = 5\ \text{V}$                       | $h_{FE}$      | 70     | -    | -    | -                |
| Collector-emitter saturation voltage <sup>1)</sup><br>$I_C = 10\ \text{mA}, I_B = 0.5\ \text{mA}$ | $V_{CEsat}$   | -      | -    | 0.3  | V                |
| Input off voltage<br>$I_C = 100\ \mu\text{A}, V_{CE} = 5\ \text{V}$                               | $V_{i(off)}$  | 0.4    | -    | 0.8  |                  |
| Input on voltage<br>$I_C = 2\ \text{mA}, V_{CE} = 0.3\ \text{V}$                                  | $V_{i(on)}$   | 0.5    | -    | 1.4  |                  |
| Input resistor                                                                                    | $R_1$         | 3.2    | 4.7  | 6.2  | $\text{k}\Omega$ |
| Resistor ratio                                                                                    | $R_1/R_2$     | 0.09   | 0.1  | 0.11 | -                |
| <b>AC Characteristics</b>                                                                         |               |        |      |      |                  |
| Transition frequency<br>$I_C = 10\ \text{mA}, V_{CE} = 5\ \text{V}, f = 100\ \text{MHz}$          | $f_T$         | -      | 150  | -    | MHz              |
| Collector-base capacitance<br>$V_{CB} = 10\ \text{V}, f = 1\ \text{MHz}$                          | $C_{cb}$      | -      | 3    | -    | pF               |

<sup>1</sup>Pulse test:  $t < 300\ \mu\text{s}$ ;  $D < 2\%$

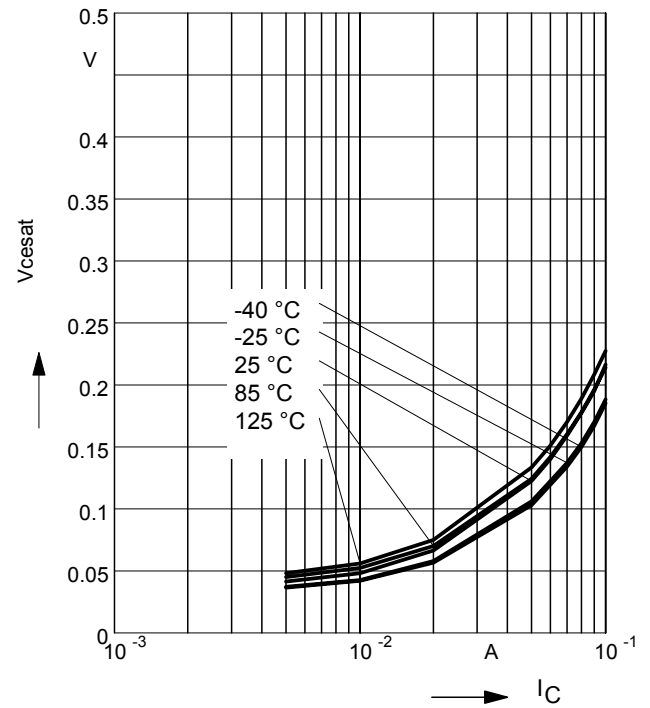
**DC current gain  $h_{FE} = f(I_C)$**

$V_{CE} = 5V$  (common emitter configuration)



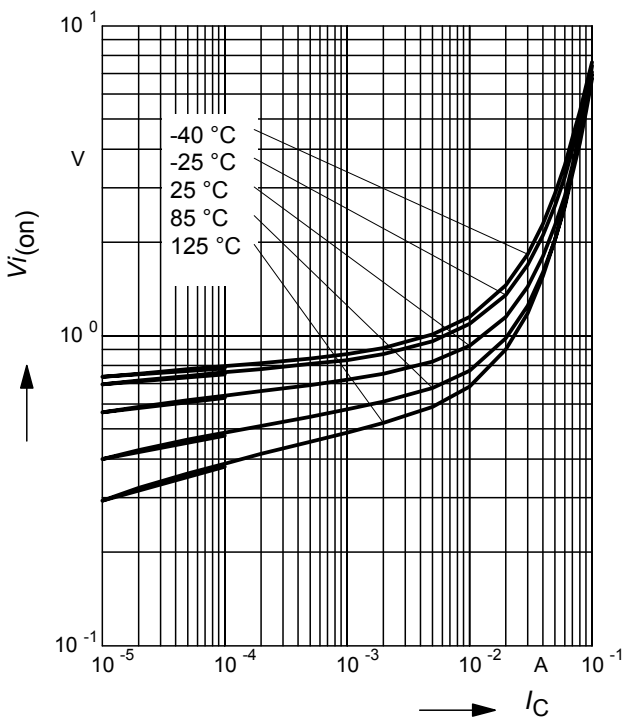
**Collector-emitter saturation voltage**

$V_{CEsat} = f(I_C), I_C/I_B = 20$



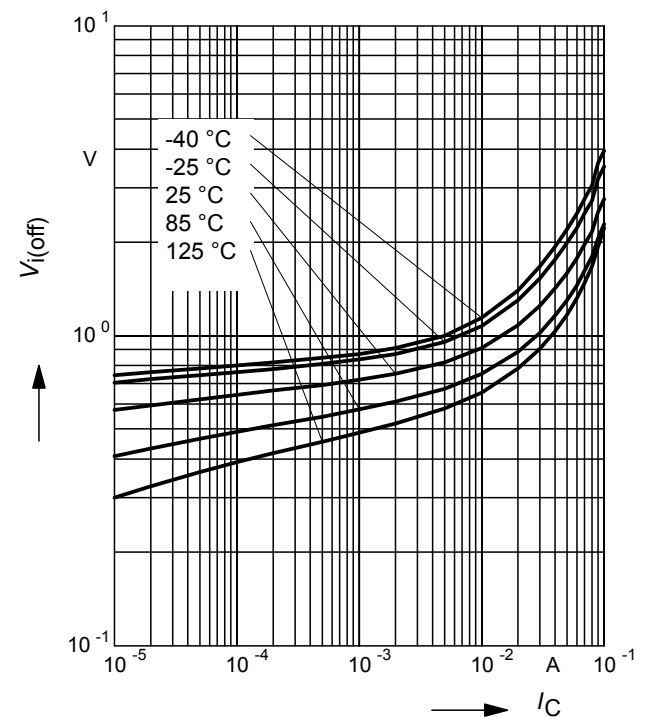
**Input on Voltage  $V_{i(on)} = f(I_C)$**

$V_{CE} = 0.3V$  (common emitter configuration)



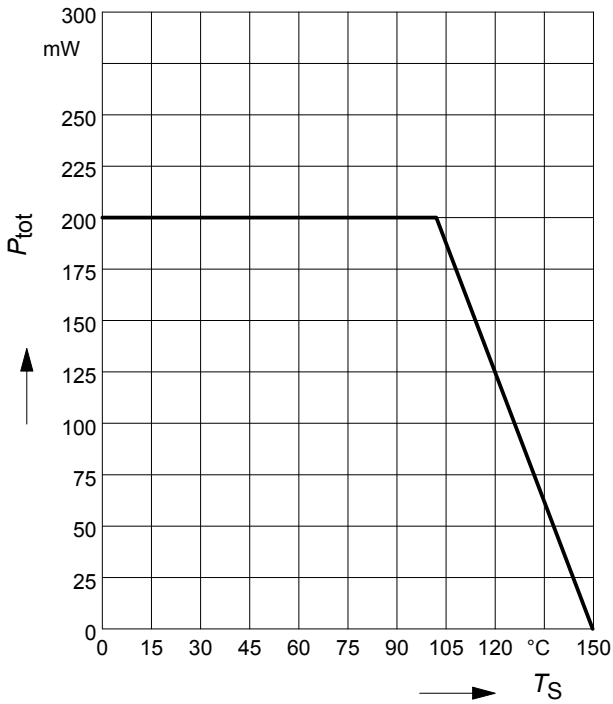
**Input off voltage  $V_{i(off)} = f(I_C)$**

$V_{CE} = 5V$  (common emitter configuration)



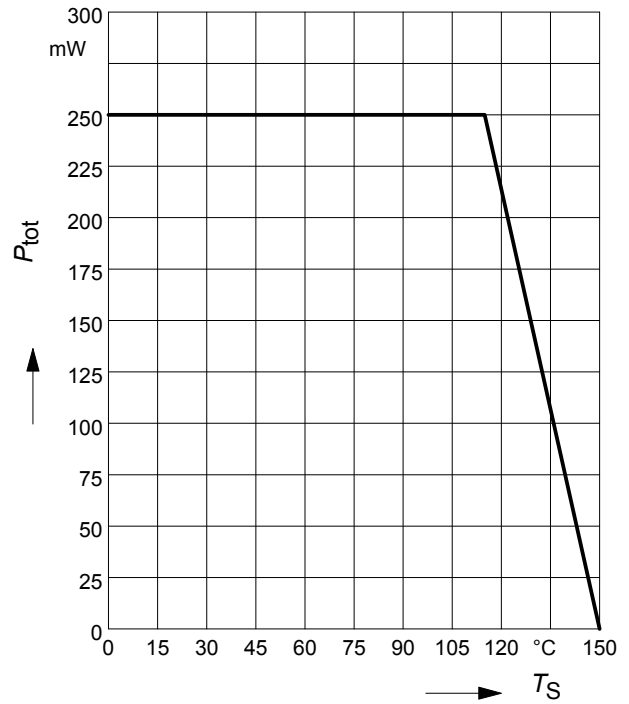
Total power dissipation  $P_{tot} = f(T_S)$

BCR116



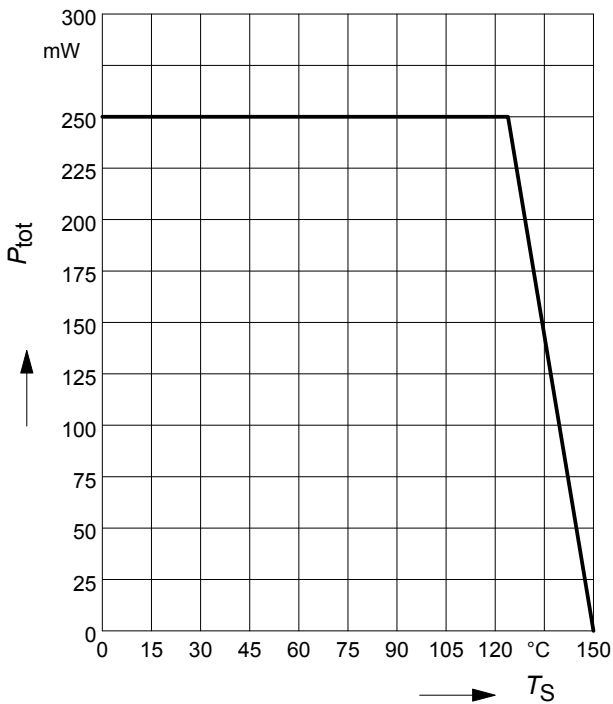
Total power dissipation  $P_{tot} = f(T_S)$

BCR116S



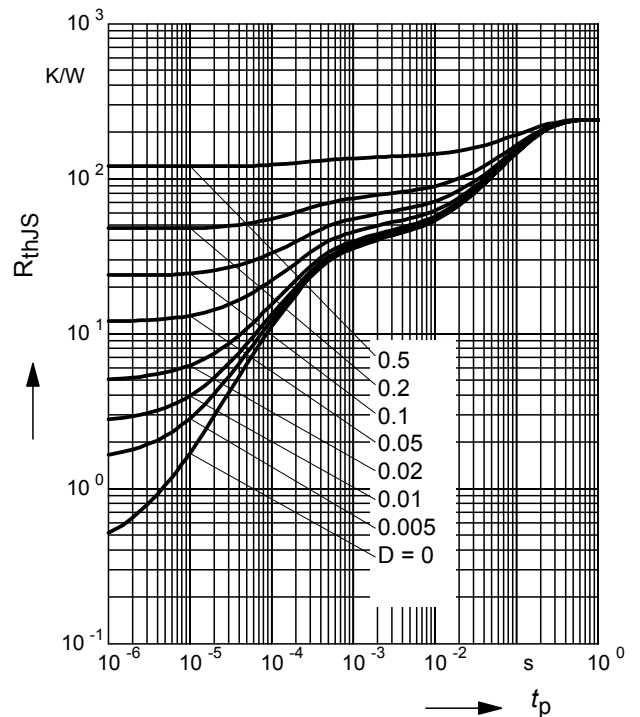
Total power dissipation  $P_{tot} = f(T_S)$

BCR116W



Permissible Pulse Load  $R_{thJS} = f(t_p)$

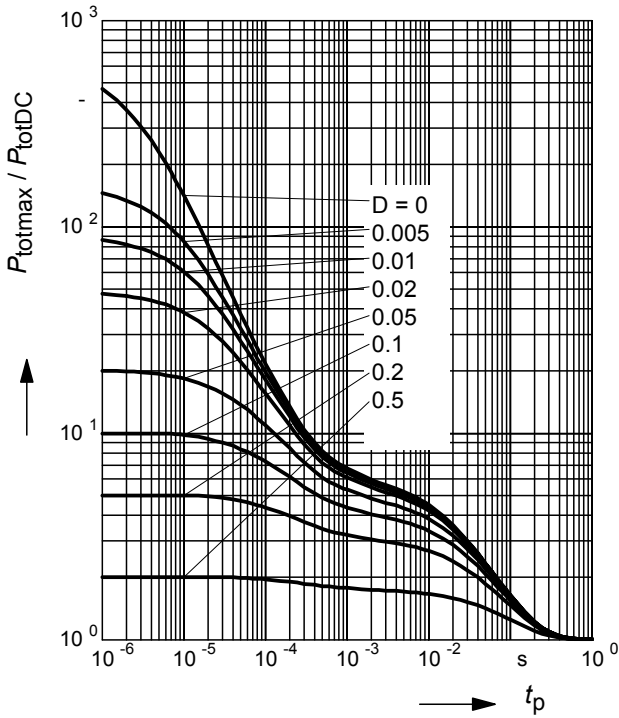
BCR116



**Permissible Pulse Load**

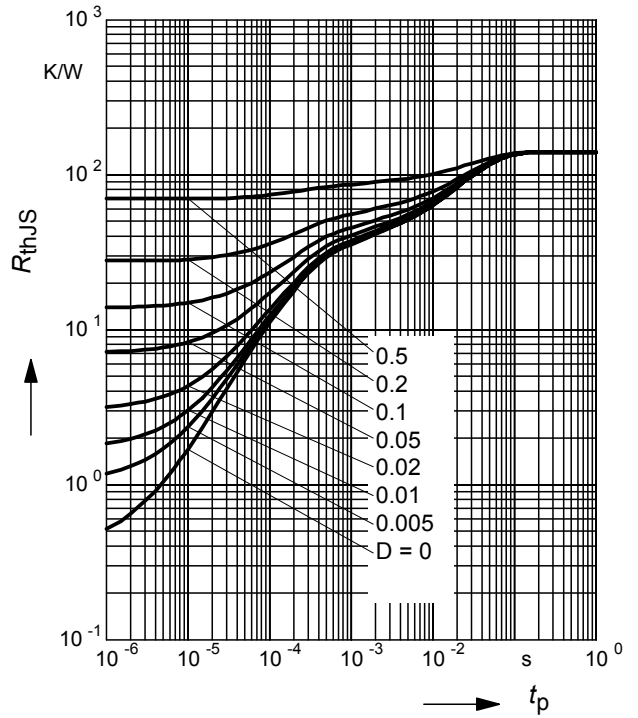
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR116



**Permissible Puls Load  $R_{\text{thJS}} = f(t_p)$**

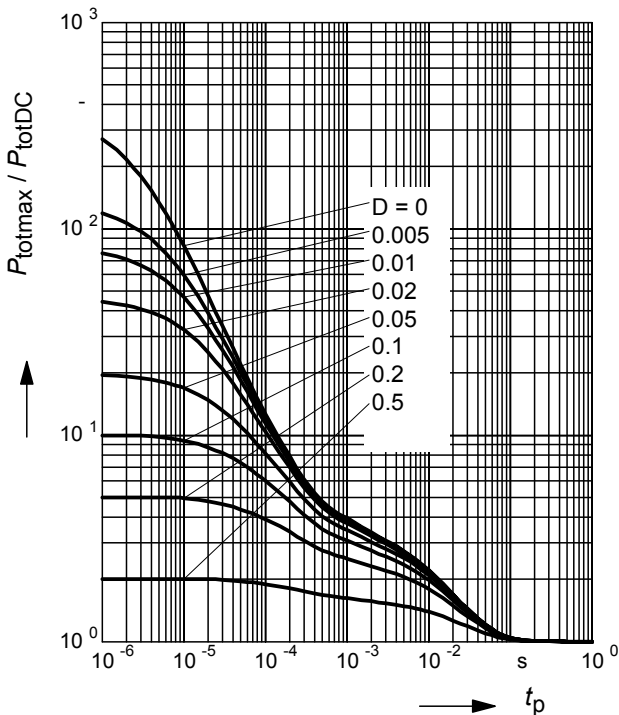
BCR116S



**Permissible Pulse Load**

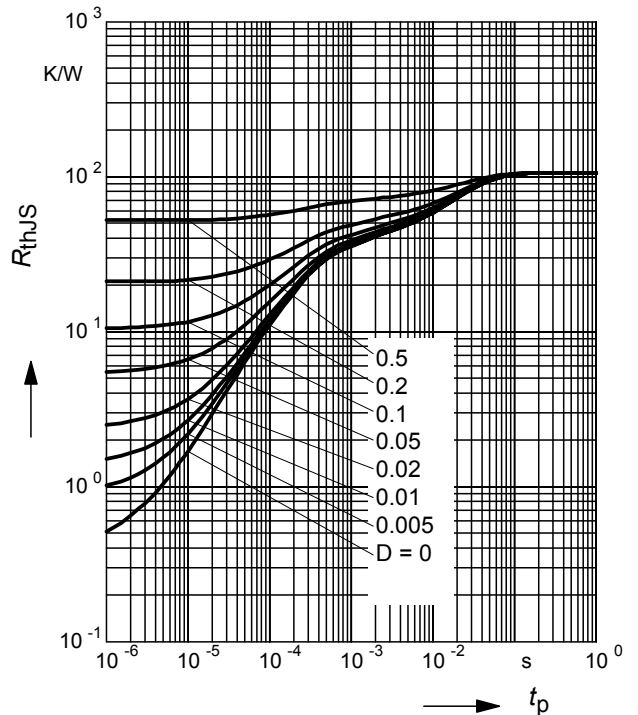
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR116S



**Permissible Puls Load  $R_{\text{thJS}} = f(t_p)$**

BCR116W



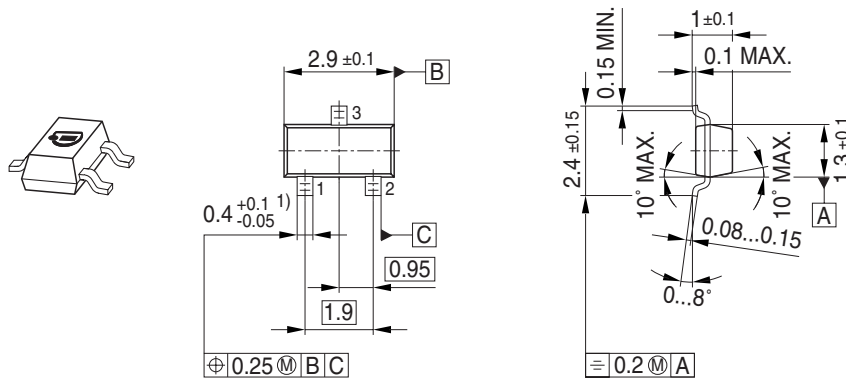
**Permissible Pulse Load**

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR116W



Package Outline



1) Lead width can be 0.6 max. in dambar area

Foot Print

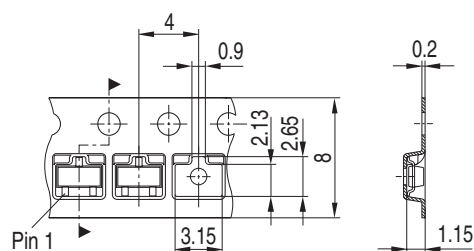


Marking Layout (Example)



Standard Packing

Reel  $\varnothing$ 180 mm = 3.000 Pieces/Reel  
 Reel  $\varnothing$ 330 mm = 10.000 Pieces/Reel





Package Outline



Foot Print

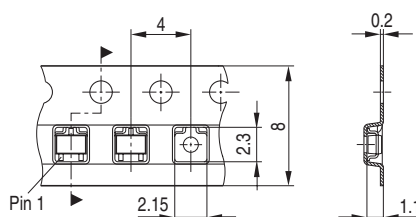


Marking Layout (Example)

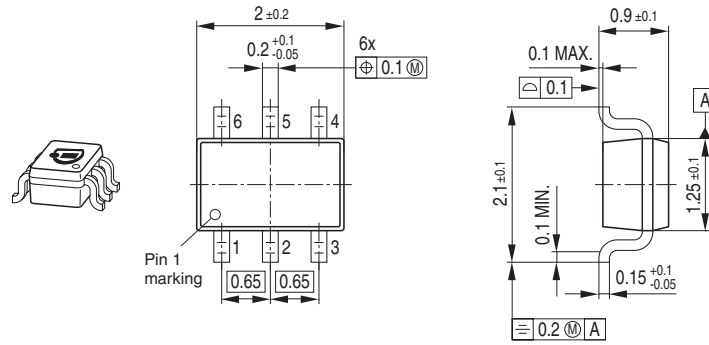


Standard Packing

Reel  $\varnothing$ 180 mm = 3.000 Pieces/Reel  
 Reel  $\varnothing$ 330 mm = 10.000 Pieces/Reel



Package Outline



Foot Print



Marking Layout (Example)

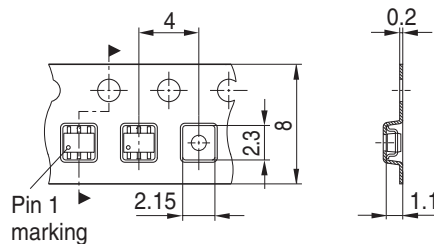
Small variations in positioning of Date code, Type code and Manufacture are possible.



Standard Packing

Reel  $\varnothing$ 180 mm = 3.000 Pieces/Reel  
 Reel  $\varnothing$ 330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.



**Edition 2009-11-16**

**Published by  
Infineon Technologies AG  
81726 Munich, Germany**

**© 2009 Infineon Technologies AG  
All Rights Reserved.**

### **Legal Disclaimer**

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

### **Information**

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office ([<www.infineon.com>](http://www.infineon.com)).

### **Warnings**

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

## Данный компонент на территории Российской Федерации

### Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9